FILING DATE

March 9, 1998

GROUP ART

2814

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB Class	FILING DATE IF APPROP.
ON.	. AA .	5,855,962	1/5/99	COTE et al.	B05D3	02	
ON	АВ	5,817,582	10/6/98	MANIAR	H01L 21	469	
ON	AC	5,569,618	10/29/96	MATSUBARA	H01L 21	8242	
ON	AD	5,186,745	2/16/93	MANIAR	C090 183	06	

FOREIGN PATENT DOCUMENTS

					0110	TRANSL	ATION
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	YES	NO
			-	<u> </u>			

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

EXAMINER	<i>0</i> √	DATE CONSIDERED	4/4/00	

O MIN 30 MAN LEGISLAND

SHEET	1	OF	1	

FORM PT	0-1/	<i>.</i> o

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO. 2933SE-11-CIP-2 SERIAL NO. 09/037,674

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)

APPLICANT

MIZUHARA et al.

FILING DATE

March 9, 1998

GROUP ART

2814

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROP.
0~	AA	4,962,052	10/9/90	ASAYAMA et al.	437	31	
0~	AB	5,930,624	7/27/99	MURATA et al.	438	253	

FOREIGN PATENT DOCUMENTS

					OUD.	TRANSL	MOITA.
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	YES	NO
				<u> </u>		х	
	\						

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

EXAMINER	on	DATE CONSIDERED	4/4/00	



SHEET	1	OF	2	

FORM	PTO-	1449
------	------	------

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO. 2933SE-11-CIP-2

SERIAL NO. 09/037,674

INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)

APPLICANT MIZUHARA et al.

FILING DATE GROUP ART

March 9, 1998

2814

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROP.

FOREIGN PATENT DOCUMENTS

							TRANS	LATION
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB Class	YES	NO
ON	AA	62-60242	3/16/87	Japan	H01L21	88		х
ON	АВ	1-199456	8/10/89	Japan	H01L21	90		х
ON	AC	2-7451	1/11/90	Japan	H01L21	90		х
0~	AD	2-26055	1/29/90	Japan	H01L21	90		х
∂N⁄	AE	2-253643	10/12/90	Japan	H01L21	90		х
ON	AF	3-101130	4/25/91	Japan	H01L21	314		х
0~	AG	4-234149	8/21/92	Japan	H01L21	90		х
ON	АН	4-317358	11/9/92	Japan	H01L21	90		x
2N	AI	5-74963	3/26/93	Japan	H01L21	90		х
0~	AJ	5-198523	8/6/93	Japan	H01L21	265		х
ON	AK	6-275229	9/30/94	Japan	H01J37	317		х

EXAMINER	ON	DATE CONSIDERED	9/1/00	





SHEET	2	OF	2
-------	---	----	---

FORM PTO-1449

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE ATTY. DOCKET NO. 2933SE-11-CIP-2 SERIAL NO. 09/037,674

INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)

APPLICANT MIZUHARA et al.

FILING DATE March 9, 1998 GROUP ART

2814

0N	AL	6-349950	12/22/94	Japan	H01L21	90	х
2N	АМ	7-99195	4/11/95	Japan	H01L21	3205	х
IN	AN	8-17770	1/19/96	Japan	H01L21	304	×
on	AO	8-64561	3/8/96	Japan	H01L21	304	х

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

•	
•	

RECEIVED

NOV 19 1999

TECHNOLOGY CENTER 2800

EXAMINER	0~	DATE CONSIDERED	4/4/00	
			man with MDED 400. Deau	ine through citation

SHEET	1	OF	1	

FORM PTO-1449	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DOCKET	NO. 2933SE-11-CIP-2	SERIAL NO. 09/037,674
INFORMATION DI (Use several s	APPLICANT MIZUHARA et al.			
i. (2)		FILING DATE March S), 1998	GROUP ART 2814

JUN 2 9 1999 CS JUN

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROP.
ou	AA	5,084,412	1/92	Nakasaki	257	762	
IN	AB	5,479,054	12/95	Tottori	257	760	
dN	AC	5,753,975	5/98	Matsuno	257	760	

FOREIGN PATENT DOCUMENTS

						TRANSLATION	
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	YES	NO
AD							
AE							

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

AF	JUL 0 2 1999
AG	
АН	TECHNOLOGY CENTER 2800
	·

				
EXAMINER	0~	DATE CONSIDERED	4/4/a	



SHEET	1	OF	1

FORM PTO-1449

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE ATTY. DOCKET NO. 2933SE-11-CIP-2 SERIAL NO. 09/037,674

INFORMATION DISCLOSURE STATEMENT

(Use several sheets if necessary)

MIZUHARA et al.

FILING DATE

APPLICANT

March 9, 1998

GROUP ART

2814

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB Class	FILING DATE IF APPROP.
•	AA						
	AB						
	AC						

FOREIGN PATENT DOCUMENTS

							TRANSL	ATION
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	YES	NO
ON.	AD	4-307934 (A)	10/30/92	JAPAN				х
,	ΑE	-						
				·				

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

	 pro * 25
AF	P. 16
AG	
AH	31
	S = K
	÷D 7:27 7:27
	W. C.

EXAMINER	01	DATE CONSIDERED	4/4/00	

			SHEET1 OF *:1
FORM PTO-1449	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DOCKET NO. 2933SE-11-CIP-2	SERIAL NO. 09/037,674
SUPPLEMENTAL INFORMATION (Use sever <u>al sh</u> eets		APPLICANT MIZUHARA et a	ι
OIPE	6	FILING DATE March 9, 1998	GROUP ART 2814
MAY 1 4 1999	U.S. PATENT	DOCUMENTS	

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROP.
0~	AA	5,153,680	10/06/92	NAITO ET AL.	357	8	
0~	АВ	3,747,203	07/24/73	SHANNON	29	578	
0N	AC	5,166,768	11/24/92	110	257	523	

FOREIGN PATENT DOCUMENTS

						SUB	TRANSL	ATION
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	CLASS	YES	NO
0V	√ AD	4,218,495 A1	12/10/92	GERMANY			>x	
	AE	(

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

AF	
AG	
АН	
	RECEIVED

WAY 1 9 1999

TECHNOLOGY CENTER 2800

EXAMINER	ON	DATE CONSIDERED	4/4/00
	ial if reference considered, whether or not ci		





GROUP 2100 HEET ____ OF ___2

FORM PTO-1449

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO. 2933SE-11-CIP-2

SERIAL NO. 09/037,674

INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)

MIZUHARA et al.

FILING DATE

APPLICANT

March 9, 1998

2814

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB Class	FILING DATE IF APPROP.
<i>U</i> ~	AA	4,676,867	06/30/87	Elkins et al.	156	643	
0N	AB	4,775,550	10/04/88	Chu et al.	427	38	
0N	AC	4,885,262	12/05/89	Ting et al.	437	231	
0~	AD	4,983,546	01/08/91	Hyun et al.	437	231	
dN	AE	5,003,062	03/26/91	Yen	437	231	
0~	AF	5,106,787	04/21/92	Yen	437	231	
<i>کہ</i> د	AG	5,192,697	03/09/93	Leong	437	37	
0~	AH	5,352,630	10/04/94	Kim et al.	437	195	
0~	AI	5,429,990	07/04/95	Liu et_al.	437	190	
0~	LA	5,496,776	03/05/96	Chien et al.	437	231	
0,~	AK	5,549,786	08/27/96	Jones et al.	156	662.1	

FOREIGN PATENT DOCUMENTS

							TRANSI	ATION
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	YES	NO
0~	AL	1-307247	12/12/89	Japan				х
0N	АМ	5-226334	3/9/93	Japan				х
2N	AN	2-101532	8/13/90	Japan				×
θ√/	AO	2-235358	9/18/90	Japan				х

EXAMINER	0.N		DATE CONSIDERED	4/4/00	
*EVAMINED. Initia	if notonone considered	whether or not cits	tion is in conforman	ce with MPEP 600. Draw line through cits	tion



RECEIVED FEB 0 4 1999

GRAUP 2100 -

FORM PTO-1449

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO. 2933SE-11-CIP-2

SERIAL NO. 09/037,674

INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)

APPLICANT

MIZUHARA et al.

FILING DATE

March 9, 1998

2814

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

0~	АР	Wang et al., "A Study of Plasma Treatments on Siloxane SOB," IEEE VMIC Conference, June 7-8, 1994, pp. 101- 107.
0N	AQ	Chiang et al., "Defects Study on Spin on Glass Planarization Technology, IEEE VMIC Conference, June 15-16, 1987, pp. 404-412.
1~	AR	Lai-Juh Chen, et al., "Fluorine-Implanted Treatment (FIT) SOG for the Non-Etchback Intermetal Dielectric," IEEE VMIC Conference, June 7-8, 1994, pp. 81-86.
ON	AS	Moriya et al., "Modification Effects in Ion-Implanted SiO ₂ Spin-on-Glass," <u>J. Electrochem. Soc.</u> , Vol. 140, No. 5, May 1993, pp. 1442-1450.
0,1	AT	Matsuura et al., "An Advanced Interlayer Dielectric System with Partially Converted Organic SOG Using Plasma Treatment," IEEE VMIC Conference, June 8-9, 1993, pp. 113-115.
0N	AU	Ishida et al., "Mechanism for AlSiCu Alloy Corrosion," <u>Jpn. J. Appl. Phys.</u> , Vol. 31 (1992), pp. 2045-2048.
<i>∂</i> N	AV	Doki et al., "Moisture-Blocking Mechanism of ECR-Plasma," IEEE VMIC Conference, June 7-8, 1994, pp. 235-139.
0	AW	Shimokawa et al., "Suppression of MOSFET hot carrier degradation by P-SiO underlayer," <u>The Institute of</u> <u>Electronics. Information and Communication Engineers</u> ," Technical Report of IEICE, SDM92-133 (1992-12), pp. 89-94.
0 ~/	AX	Murase et al., "Dielectric Constant of Silicon Dioxide Deposited by Atmospheric-Pressure Chemical Vapor Deposition Using Tetraethylorthosilicate and Ozone," <u>Jpn. J. Appl. Phys.</u> , Vol. 33 (1994), pp. 1385-1389.

		,		
EXAMINER	ON	DATE CONSIDERED	4/4/00	



SHEET	1	OF	1

FORM PTO-1449

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE ATTY. DOCKET NO. 2933SE-11-CIP-2 SERIAL NO. 09/037,674

INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)

APPLICANT MIZUHARA et al.

FILING DATE March 9, 1998

GROUP ART

2814

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROP.
ON	AA	5,153,680	10/06/92	NAITO ET AL.	357	8	
0~	АВ	3,747,203	07/24/73	SHANNON	29	578	
0,1	AC	5,166,768	11/24/92	110	257	523	
-				RECEIV	#U		

				JAN N 8	1999			
			FORE	IGN PATENT DOCUMENTS				
	T 1			- GROUP	2100 -	1		
						CUB	TRANS	LATION
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	YES	NO
DN	AD	4,218,495 A1	12/10/92	GERMANY			X	
	AE							
					Ĭ			

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

AF	
AG	
АН	

EXAMINER	0~	DATE CONSIDERED	4/4/00	